

AMENDMENT UNDER 37 C.F.R. § 1.116  
EXPEDITED PROCEDURE  
GROUP 1775  
PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q80989

Takayuki SUZUKI

Appln. No.: 10/821,957

Group Art Unit: 1775

Confirmation No.: 2365

Examiner: LANGMAN, JONATHAN C.

Filed: April 12, 2004

For: SELF-SUPPORTED NITRIDE SEMICONDUCTOR SUBSTRATE AND ITS  
PRODUCTION METHOD, AND LIGHT-EMITTING NITRIDE SEMICONDUCTOR  
DEVICE USING IT

RESPONSE/REQUEST FOR WITHDRAWAL OF FINALITY OF ACTION

MAIL STOP AF

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

In response to the Office Action dated July 20, 2007, please consider the following

Applicant's response.

REMARKS

Review and reconsideration on the merits are requested.

The Invention

Applicant respectfully submits, in summary, that the prior art, alone or in combination, does not teach all the limits of claim 1. Specifically, the prior art does not teach a self-supported nitride semiconductor substrate simultaneously satisfying the conditions that:

It has a diameter of 10 mm or more;